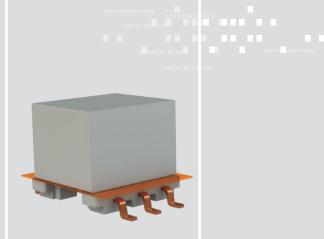
New

GDAU-003

Gate-Drive Transformer 2:1 200Vus

INDUCTIVE COMPONENTS / GATE-DRIVE TRANSFORMER





APPLICATIONS

> Automotive PFC stage in onboard battery chargers

FEATURES

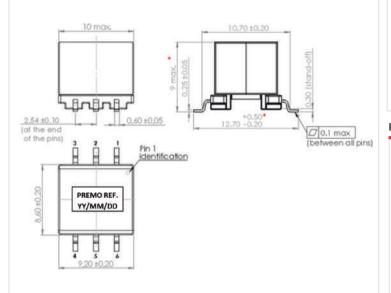
- > Gate-Drive transformer for thyristors driver
- > Working voltage up to 500Vdc
- > Functional insulation at 500V
- > ETmax product of 200Vµs
- > Wide operating temperature range -40 to +105°C
- > UL94 and RoHS materials
- > AEC-Q200 qualified
- > Weight: approx 2grams

OPERATION

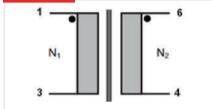
> Thyristors driver control where only functional insulation is needed

SPECIFICATIONS

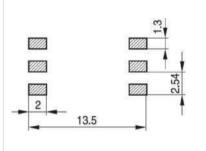
DIMENSIONS



ELECTRICAL DIAGRAM



RECOMMENDED PAD-LAYOUT



ELECTRICAL SPECIFICATIONS

INDUCTANCE at 25°C	
L ₁₋₃ (10kHz/50mVac)	3mH ≤ 5mH TYP ≤ 7mH
TURN-RATIO	
N ₁₋₃ : N ₆₋₄ (10kHz/1Vac)	2:1
DC RESISTANCE at 25°C	
DCR ₁₋₃	1.2Ω MAX (0.98Ω TYP)
DCR ₄₋₆	0.6Ω ΜΑΧ (0.45Ω ΤΥΡ)
LEAKAGE INDUCTANCE	
Llk ₁₋₃ (100kHz/1Vac)	13μH MAX
STRAY CAPACITANCE	
CPS (100kHz/1Vac)	15pF MAX
DIELECTRIC STRENGTH	
Between Windings	500Vac (50Hz/3mA/1min)